OTA TESTREPORT

ISSUED BY Shenzhen BALUN Technology Co., Ltd.

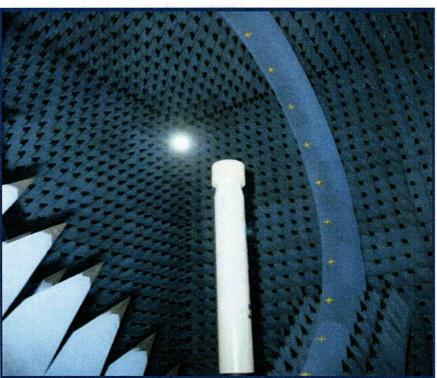


FOR

Antenna

ISSUED TO SHEN ZHEN HOPE MICROELECTRONICS CO., LIMITED

30/F, Block A, Building 8, Phase 3, Vanke Cloud City, Liuxin 4th street, XiLi, Nanshan, Shenzhen 518055, China



Approved by: Liao Jianming (Technical Director) Date 741. 23, 2021

Report No: BL-SZ2170362-901 Antenna EUT Name:

Model Name: RFM75C-S3

Brand Name: N/A

Test Standard: ANSI/IEEE Std 149-1979

Maximum: Gain: 0.02 (dBi)

Efficiency: 36%

Test Date: Jul. 09, 2021

Date of Issue:

Jul. 23, 2021

NOTE: This test report of test results only related to the testing samples, which can be duplicated completely for the legal use with the approval of the applicant; it shall not be reproduced except in full, without the written approval of Shenzhen BALUN Technology Co., Ltd. Any objections should be raised within thirty days from the date of issue. To validate the report, please visit BALUN website.

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Revision History

Version Rev. 01

Issue Date <u>Jul. 23, 2021</u> Revisions

Initial Issue

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1 Administrative Data (GENERAL INFORMATION)

1.1 Identification of the Testing Laboratory

Company Name	Shenzhen BALUN Technology Co., Ltd.
Address	Block B, 1st FL, Baisha Science and Technology Park, Shahe Xi Road,
Address	Nanshan District, Shenzhen, Guangdong Province, P. R. China
Phone Number	+86 755 6685 0100

1.2 Identification of the Responsible Testing Location

Test Location	Shenzhen BALUN Technology Co., Ltd.
Addross	Block B, 1st FL, Baisha Science and Technology Park, Shahe Xi Road,
Address	Nanshan District, Shenzhen, Guangdong Province, P. R. China
	All measurement facilities used to collect the measurement data are
Description	located at Block B, FL 1, Baisha Science and Technology Park, Shahe
Description	Xi Road, Nanshan District, Shenzhen, Guangdong Province, P. R.
	China 518055

1.3 Laboratory Condition

Ambient Temperature	19℃ to 25℃
Ambient Relative Humidity	45% to 55%
Ambient Pressure	100 kPa to 102 kPa

1.4 Announce

- (1) The test report reference to the report template version v2.2.
- (2) The test report is invalid if not marked with the signatures of the persons responsible for preparing and approving the test report.
- (3) The test report is invalid if there is any evidence and/or falsification.
- (4) The results documented in this report apply only to the tested sample, under the conditions and modes of operation as described herein.
- (5) This document may not be altered or revised in any way unless done so by BALUN and all revisions are duly noted in the revisions section.
- (6) Content of the test report, in part or in full, cannot be used for publicity and/or promotional purposes without prior written approval from the laboratory.
- (7) The laboratory is only responsible for the data released by the laboratory, except for the part provided by the applicant.



2 PRODUCT INFORMATION

2.1 Applicant Information

Applicant	SHEN ZHEN HOPE MICROELECTRONICS CO., LIMITED
Address	30/F, Block A, Building 8, Phase 3, Vanke Cloud City, Liuxin 4th street,
Addiess	XiLi, Nanshan, Shenzhen 518055, China

2.2 Manufacturer Information

Manufacturer	SHEN ZHEN HOPE MICROELECTRONICS CO., LIMITED	
Addross	30/F, Block A, Building 8, Phase 3, Vanke Cloud City, Liuxin 4th street,	
Address	XiLi, Nanshan, Shenzhen 518055, China	

2.3 Factory Information

Factory	N/A
Address	N/A

2.4 General Description for Equipment under Test (EUT)

EUT Name	Antenna
Model Name Under Test	RFM75C-S3
Antenna Type	PCB Antenna
Dimensions	12mm×8mm

2.5 Ancillary Equipment

Note: Not Applicable

2.6 Technical Information

Frequency Range	2400MHz~ 2483.5MHz	
Toot Fraguencies	2400MHz, 2410MHz, 2420MHz, 2430MHz, 2440MHz, 2450MHz,	
Test Frequencies	2460MHz, 2470MHz, 2480MHz, 2483.5MHz	



3 SUMMARY OF TEST RESULTS

3.1 Test Standards

No.	Identity	Document Title
1	ANSI/IEEE Std 149-1979	IEEE Standard Test Procedures for Antennas

3.2 Test Verdict

Report Section	Description	Remark
ANNEX A.1	Gain and Efficiency	-
ANNEX B	Radiation Pattern	

3.3 Test Uncertainty

The uncertainty is calculated using the methods suggested in the "Guide to the Expression of Uncertainty in Measurement" (GUM) published by ISO.

Item	Uncertainty
VSWR(S11)	±0.61
Gain	\pm 1.92dB



4 GENERAL TEST CONFIGURATIONS

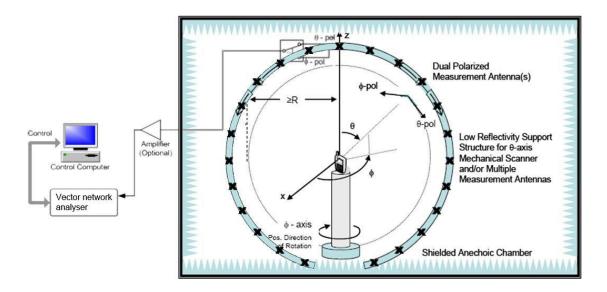
4.1 Test Condition

	Selected Values During Tests				
Environment Parameter	Ambient Pressure(KPa)	Temperature(°C)	Voltage	Relative Humidity (%)	
Normal Temperature, Normal Voltage (NTNV)	100 to 102	19 to 25	N/A	45 to 55	

4.2 Test Equipment List

Description	Manufacturer	Model	Serial No.	Cal. Date	Cal. Due
Vector Network	Agilent	E5071C	MY46103472	2021.01.26	2022.01.25
Analyzer	Agiletit	L307 10	101140103472	2021.01.20	2022.01.23
SG24 Multi-probe			1101055		
Antenna Measurement	SATIMO	SG24-L	1101855- 0001	2021.05.23	2022.05.24
System			0001		

4.3 Test Setup





ANNEX A TEST RESULTS

A.1 Gain and Efficiency

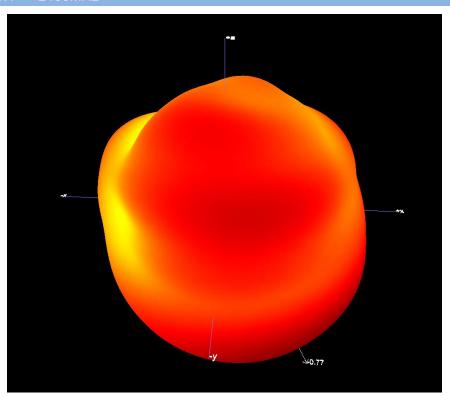
Frequency	Gain (dBi)	Efficiency (%)
2400MHz	-0.77	28
2410MHz	-0.38	30
2420MHz	-0.31	31
2430MHz	-0.24	32
2440MHz	-0.19	33
2450MHz	-0.22	33
2460MHz	-0.22	34
2470MHz	-0.10	35
2480MHz	0.02	36
2483.5MHz	0.02	36



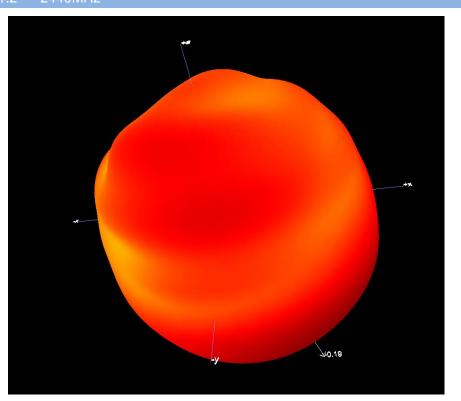
ANNEX B RADIATION PATTERN

3D Pattern

B.1.1 2400MHz

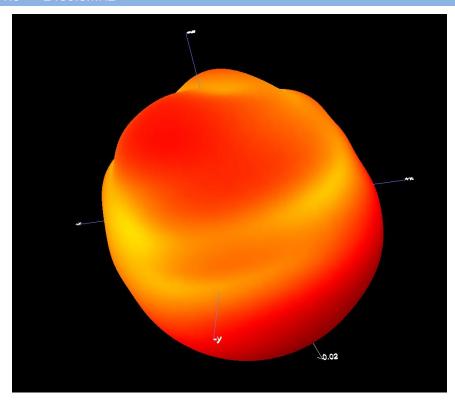


B.1.2 2440MHz



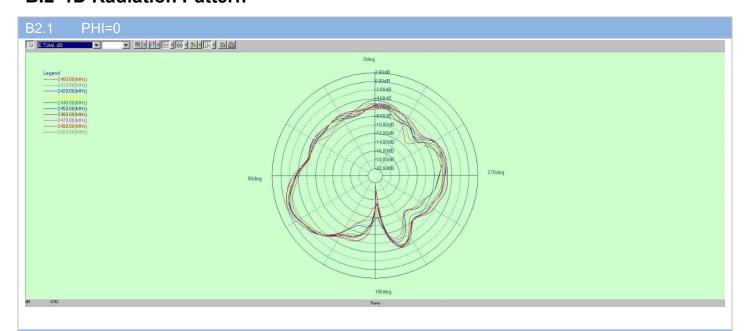


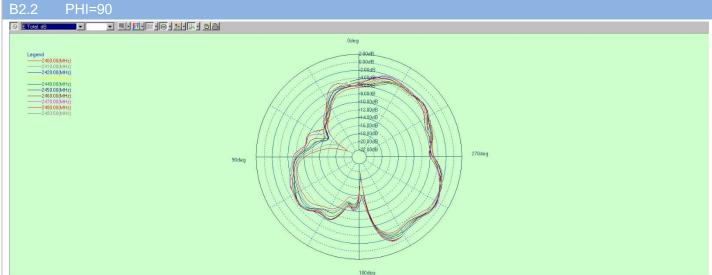
B.1.3 2483.5MHz

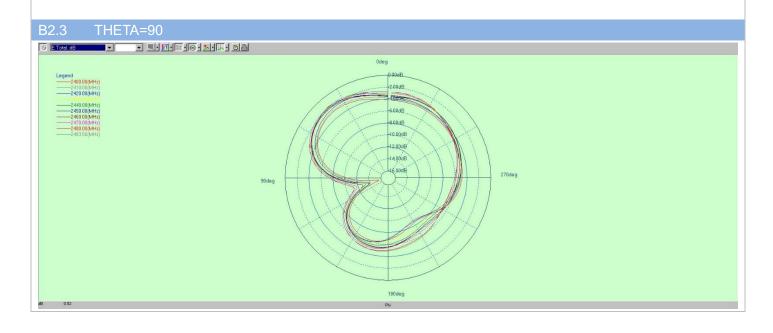




B.2 1D Radiation Pattern

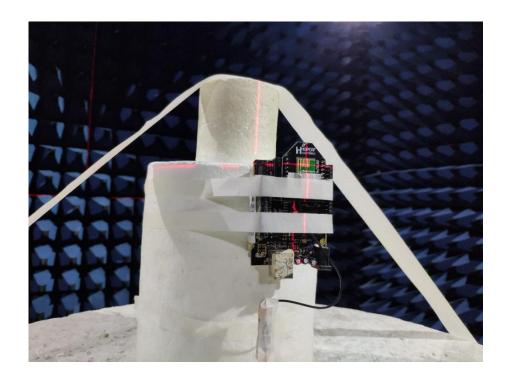


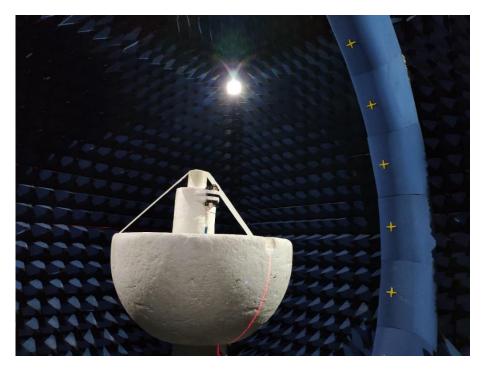






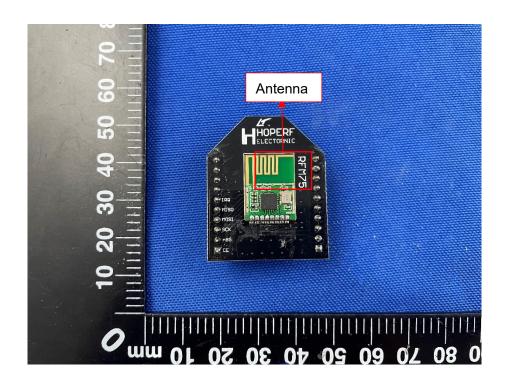
ANNEX C TEST SETUP PHOTO







ANNEX D EUT PHOTO



--END OF REPORT--